NSN 5962-01-287-8530

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-287-8530 **Body Length:** Between 1.435 inches and 1.485 inches **Body Width:** Between 0.515 inches and 0.599 inches **Body Height:** Between 0.140 inches and 0.180 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 7010-01-211-9822 **Features Provided:** Hermetically sealed and programmable and ultraviolet erasable and w/enable and bidirectional and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 25 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.6 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

NSN 5962-01-287-8530

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0